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DATA SHEET

For a complete data sheet, please also download:

- The IC04 LOCMOS HE4000B Logic Family Specifications HEF, HEC
- The IC04 LOCMOS HE4000B Logic Package Outlines/Information HEF, HEC

HEF40374B
MSI
Octal D-type flip-flop with 3-state outputs

Product specification
File under Integrated Circuits, IC04

January 1995

Philips Semiconductors

PHILIPS

Octal D-type flip-flop with 3-state outputs

HEF40374B MSI

DESCRIPTION

The HEF40374B is an octal D-type flip-flop with 3-state buffered outputs with a common clock input (CP). The device is used primarily as an 8-bit positive edge-triggered storage register for interfacing with a 3-state bus. Data on the D-inputs is transferred to storage during the LOW-to-HIGH transition of the clock (CP) input. The 3-state output buffers are controlled by an active LOW output enable input ($\overline{EO}$). A HIGH on $\overline{EO}$ forces the eight outputs to a high impedance OFF-state. When $\overline{EO}$ is LOW, the data in the register appears at the outputs.

The output stages have high current output capability suitable for driving highly capacitive loads.
The device features hysteresis on the CP input to improve noise rejection.
Schmitt-trigger action in the E input makes the circuit highly tolerant to slower input rise and fall times.

The HEF40374B is pin and functionally compatible with the TTL '374' device.
Supply voltage range: 3 to 15 V.

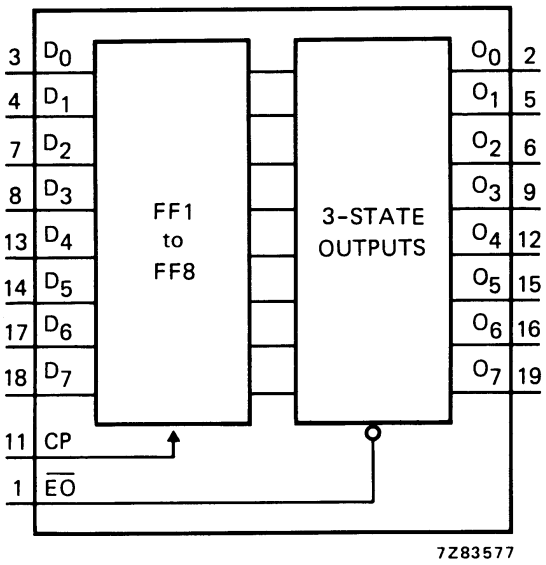


Fig.1 Functional diagram.

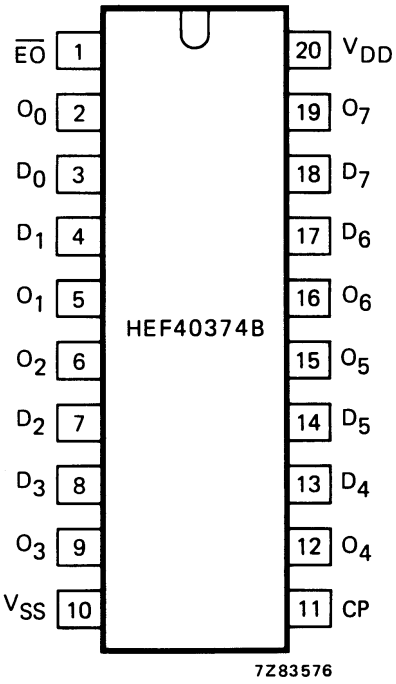


Fig.2 Pinning diagram.

HEF40374BP(N): 20-lead DIL; plastic (SOT146-1)
HEF40374BD(F): 20-lead DIL; ceramic (cerdip) (SOT152)
HEF40374BT(D): 20-lead SO; plastic (SOT163-1)
( ): Package Designator North America

PINNING

D_0 to D_7	data inputs
CP	clock input
$\overline{EO}$	output enable input (active LOW)
O_0 to O_7	3-state buffered outputs

FAMILY DATA, I_{DD} LIMITS category MSI

See Family Specifications

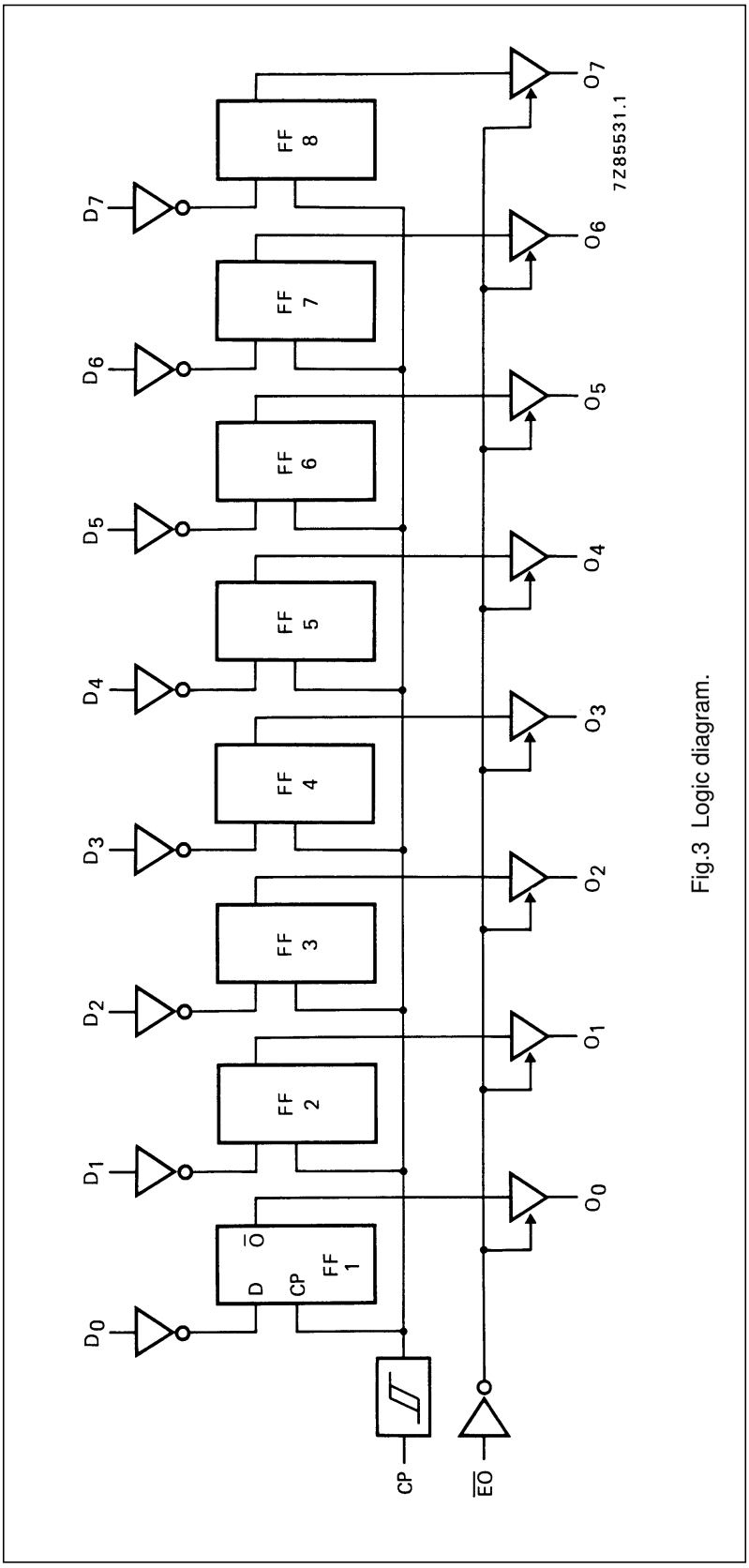


Fig.3 Logic diagram.

FUNCTION TABLE

OPERATING MODES	INPUTS			INTERNAL REGISTER	OUTPUTS O_0 TO O_7
	$\overline{EO}$	CP	D_n		
load & read register	L	⌐	l	L	L
	L	⌐	h	H	H
load register & disable outputs	H	⌐	l	L	Z
	H	⌐	h	H	Z

Notes

1. H = HIGH state (the more positive voltage)
   h = HIGH state (one set-up time prior to the LOW-to-HIGH clock transition)
   L = LOW state (the less positive voltage)
   l = LOW state (one set-up time prior to the LOW-to-HIGH clock transition)
   Z = high impedance OFF-state
   ⌐ = LOW-to-HIGH clock transition

RATINGS

Limiting values in accordance with the Absolute Maximum System (IEC 134)
See Family Specifications, except for:

D.C. current into any input	$\pm I_I$	max.	10	mA
D.C. source or sink current into any output	$\pm I_O$	max.	25	mA
D.C. current into the supply terminals	$\pm I$	max.	100	mA

DC CHARACTERISTICS

V_{SS} = 0 V

	V_{DD} V	V_{OH} V	V_{OL} V	SYMBOL	T_{amb} (°C)						
					−40		+ 25		+ 85		
					MIN.	TYP.	MIN.	TYP.	MIN.	TYP.	
Output current	5	4,6			0,75		0,6	1,2	0,45		mA
HIGH	10	9,5		$-I_{OH}$	1,85		1,5	3,0	1,1		mA
	15	13,5			14,5		15	50	15,5		mA
Output current	5	3,6			9,3		10	24	10,7		mA
HIGH	10	8,4		$-I_{OH}$	14,4		15	46	15,0		mA
	15	13,2			19,5		20	62	19,8		mA
Output current	5		0,4		2,9		2,3	5,4	1,75		mA
LOW	10		0,5	I_{OL}	9,5		7,6	17	5,50		mA
	15		1,5		30,0		25	45	19,0		mA
Hysteresis	5							220			mV
voltage at	10			V_H				250			mV
clock input (CP)	15							320			mV

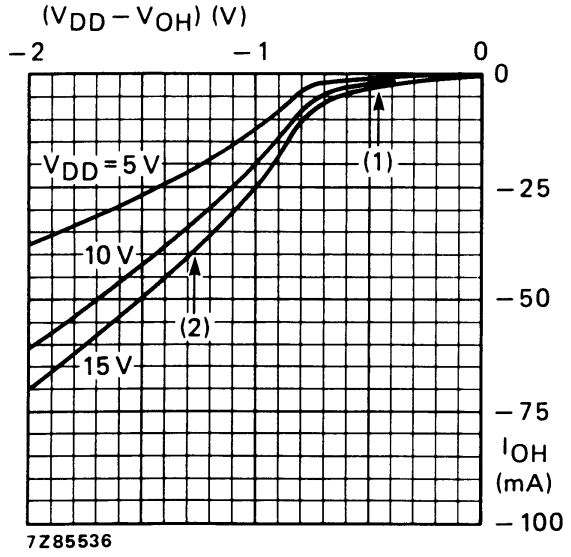
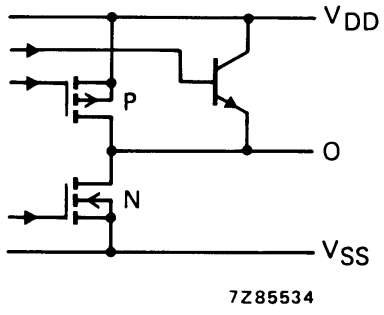


Fig.4 Typical output source current characteristic.



(1) P-channel MOS transistor conducting.
(2) P-channel MOS transistor and bipolar n-p-n transistor conducting.

Fig.5 Schematic diagram of output stage.

AC CHARACTERISTICS

V_{SS} = 0 V; T_{amb} = 25 °C; C_L = 50 pF; input transition times ≤ 20 ns

	V_{DD} V	SYMBOL	MIN.	TYP.	MAX.		TYPICAL EXTRAPOLATION FORMULA
Propagation delays							
CP → O_n	5			125	250	ns	113 ns + (0,24 ns/pF) C_L
HIGH to LOW	10	t_{PHL}		55	110	ns	54 ns + (0,01 ns/pF) C_L
	15			40	80	ns	36 ns + (0,07 ns/pF) C_L
CP → O_n	5			125	250	ns	122 ns + (0,06 ns/pF) C_L
LOW to HIGH	10	t_{PLH}		55	110	ns	53 ns + (0,03 ns/pF) C_L
	15			40	80	ns	39 ns + (0,02 ns/pF) C_L
Output transition	5			40	80	ns	see Fig.6
times	10	t_{THL}		20	40	ns	
HIGH to LOW	15			15	30	ns	
	5			30	60	ns	
LOW to HIGH	10	t_{TLH}		20	40	ns	
	15			15	30	ns	
3-state propagation delays							
Output disable times							
$\overline{EO}$ → O_n	5			60	120	ns	
HIGH	10	t_{PHZ}		30	60	ns	
	15			24	48	ns	
	5			70	140	ns	
LOW	10	t_{PLZ}		35	70	ns	
	15			30	60	ns	
Output enable times							
$\overline{EO}$ → O_n	5			65	130	ns	
HIGH	10	t_{PZH}		30	60	ns	
	15			24	48	ns	
	5			85	170	ns	
LOW	10	t_{PZL}		35	70	ns	
	15			25	50	ns	
Set-up time	5		20	0		ns	
D_n → CP	10	t_{su}	20	2		ns	
	15		20	5		ns	
Hold time	5		20	10		ns	
D_n → CP	10	t_{hold}	15	2		ns	
	15		10	0		ns	

	V_{DD} V	SYMBOL	MIN.	TYP.	MAX.	TYPICAL EXTRAPOLATION FORMULA
Minimum clock	5		50	25	ns	
pulse width; LOW	10	t_{WCPL}	25	12	ns	
	15		20	10	ns	
Maximum clock	5		25	5	MHz	
pulse frequency	10	f_{max}	6	12	MHz	
	15		8	17	MHz	

AC CHARACTERISTICS

V_{SS} = 0 V; T_{amb} = 25 °C; input transition times ≤ 20 ns

	V_{DD} V	TYPICAL FORMULA FOR P (μW)	
Dynamic power	5	$3\,775\ f_i + \sum (f_o C_L) \times V_{DD}^2$	where
dissipation per	10	$15\,700\ f_i + \sum (f_o C_L) \times V_{DD}^2$	f_i = input freq. (MHz)
package (P)	15	$40\,575\ f_i + \sum (f_o C_L) \times V_{DD}^2$	f_o = output freq. (MHz)
			C_L = load capacitance (pF)
			$\sum (f_o C_L)$ = sum of outputs
			V_{DD} = supply voltage (V)

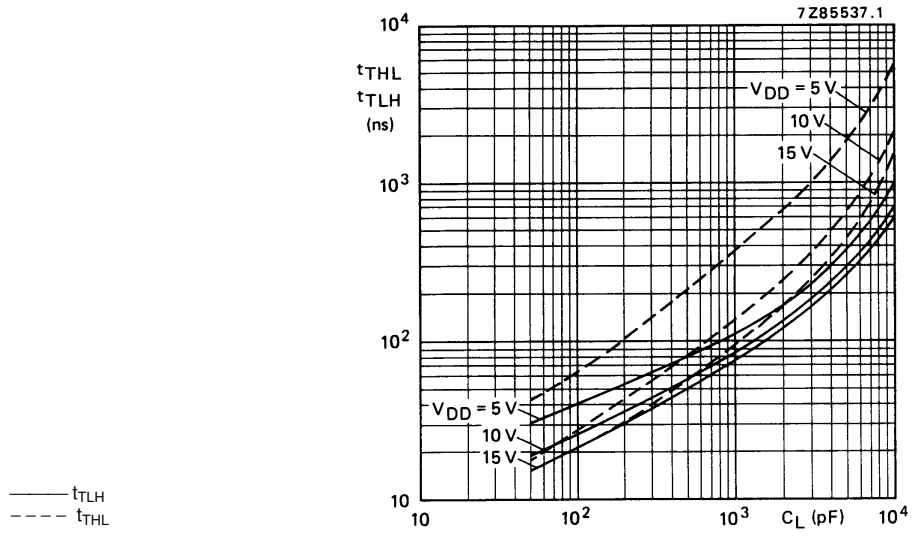


Fig.6 Output transition times as a function of the load capacitance. .